

## NCE Automotive N-Channel Super Trench II Power MOSFET

### Description

The NCEAP25N10AG uses **Super Trench II** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{DS(ON)}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification.

### Application

- Automotive application
- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

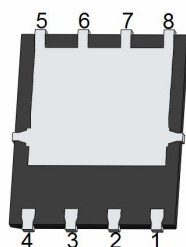
### General Features

- $V_{DS} = 100V, I_D = 32A$
- $R_{DS(ON)} = 21m\Omega$  (typical) @  $V_{GS} = 10V$
- $R_{DS(ON)} = 26m\Omega$  (typical) @  $V_{GS} = 4.5V$
- Excellent gate charge x  $R_{DS(on)}$  product(FOM)
- Very low on-resistance  $R_{DS(on)}$
- 175°C operating temperature
- Pb-free lead plating;RoHScompliant
- Halogen-free according to IEC61249-2-21
- 100% UIS tested
- 100%  $\Delta V_{ds}$  tested
- **AEC-Q101 qualified**

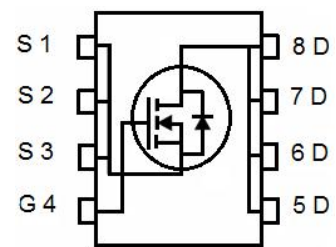
### DFN 5X6



Top View



Bottom View



Schematic Diagram

### Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
AP25N10AG	NCEAP25N10AG	DFN5X6-8L	Ø330mm	12mm	5000units

### Absolute Maximum Ratings ( $T_c = 25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	$V_{DS}$	100	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Drain Current-Continuous	$I_D$	32	A
Drain Current-Continuous( $T_c = 100^\circ C$ )	$I_D(100^\circ C)$	23	A
Pulsed Drain Current	$I_{DM}$	128	A
Maximum Power Dissipation	$P_D$	54	W
Derating factor		0.36	W/°C
Single pulse avalanche energy (Note 5)	$E_{AS}$	97	mJ
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55 To 175	°C

### Thermal Characteristic

Thermal Resistance, Junction-to-Case <sup>(Note 2)</sup>	$R_{\theta JC}$	2.78	$^{\circ}C/W$
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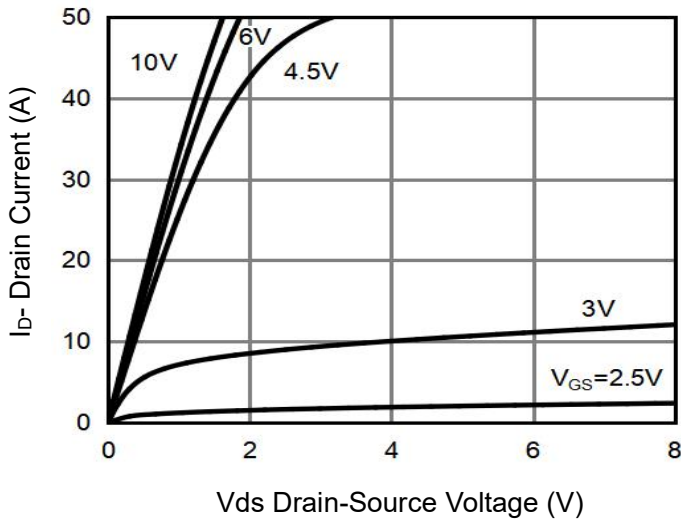
## Electrical Characteristics ( $T_C=25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
<b>Off Characteristics</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=250\mu A$	100		-	V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=100V, V_{GS}=0V$	-	-	1	$\mu A$
Gate-Body Leakage Current	$I_{GSS}$	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	$\pm 100$	nA
<b>On Characteristics</b> <sup>(Note 3)</sup>						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1.1	1.7	2.5	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=15A$	-	21	25	m $\Omega$
		$V_{GS}=4.5V, I_D=15A$	-	26	30	m $\Omega$
Forward Transconductance	$g_{FS}$	$V_{DS}=5V, I_D=15A$	-	19	-	S
<b>Dynamic Characteristics</b> <sup>(Note 4)</sup>						
Input Capacitance	$C_{iss}$	$V_{DS}=50V, V_{GS}=0V,$ $F=1.0MHz$	-	1317.6	-	pF
Output Capacitance	$C_{oss}$		-	123.9	-	pF
Reverse Transfer Capacitance	$C_{rss}$		-	19.3	-	pF
<b>Switching Characteristics</b> <sup>(Note 4)</sup>						
Turn-on Delay Time	$t_{d(on)}$	$V_{DD}=50V, I_D=15A$ $V_{GS}=10V, R_G=3\Omega$	-	13	-	nS
Turn-on Rise Time	$t_r$		-	15	-	nS
Turn-Off Delay Time	$t_{d(off)}$		-	22	-	nS
Turn-Off Fall Time	$t_f$		-	6	-	nS
Total Gate Charge	$Q_g$	$V_{DS}=50V, I_D=15A,$ $V_{GS}=10V$	-	27.6	-	nC
Gate-Source Charge	$Q_{gs}$		-	5.5		nC
Gate-Drain Charge	$Q_{gd}$		-	6.9		nC
<b>Drain-Source Diode Characteristics</b>						
Diode Forward Voltage <sup>(Note 3)</sup>	$V_{SD}$	$V_{GS}=0V, I_S=15A$	-		1.2	V
Diode Forward Current <sup>(Note 2)</sup>	$I_S$		-	-	32	A
Reverse Recovery Time	$t_{rr}$	$T_J = 25^{\circ}C, I_F = 15A$	-	40	-	nS
Reverse Recovery Charge	$Q_{rr}$	$di/dt = 100A/\mu s$ <sup>(Note 3)</sup>	-	85	-	nC

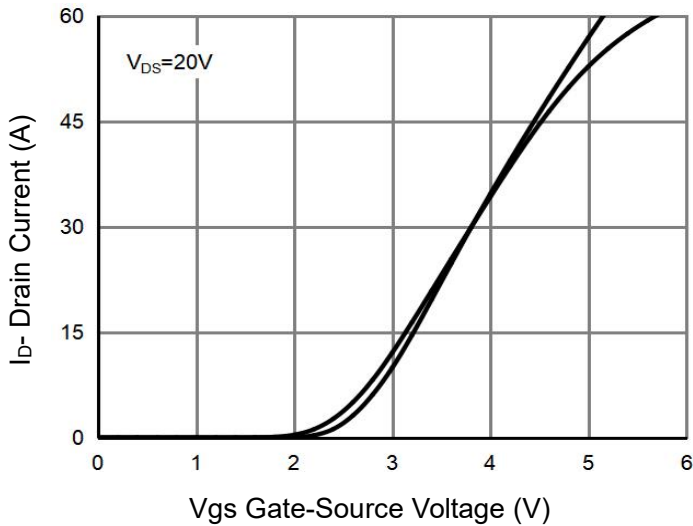
### Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board,  $t \leq 10$  sec.
3. Pulse Test: Pulse Width  $\leq 300\mu s$ , Duty Cycle  $\leq 2\%$ .
4. Guaranteed by design, not subject to production
5. EAS condition :  $T_J=25^{\circ}C, V_{DD}=50V, V_G=10V, L=0.5mH, R_G=25\Omega$

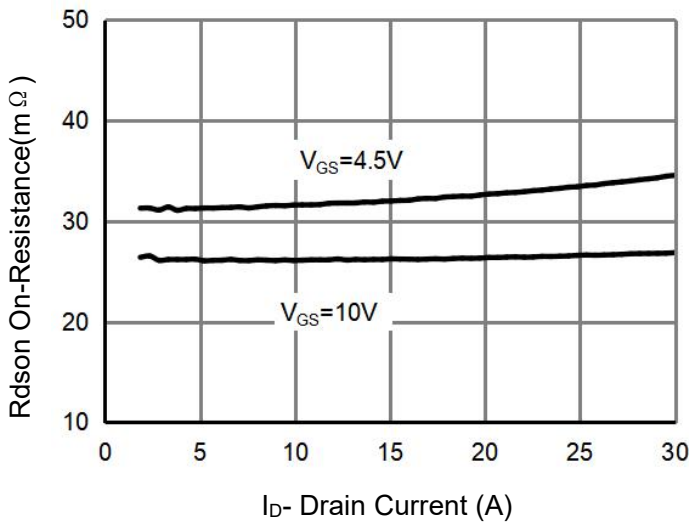
## Typical Electrical and Thermal Characteristics



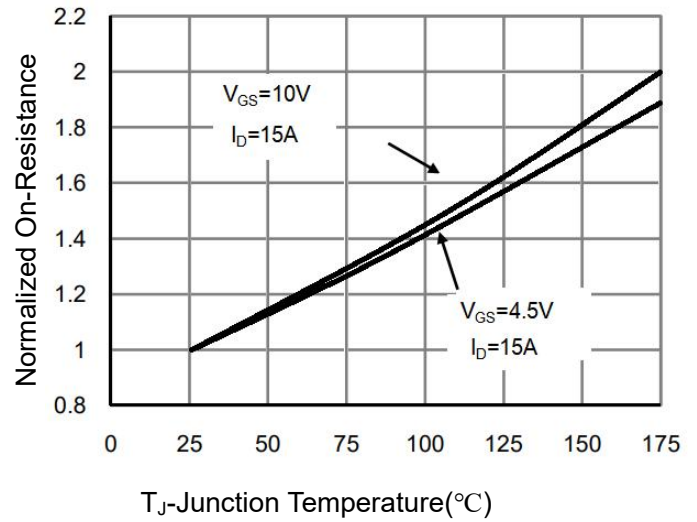
**Figure 1 Output Characteristics**



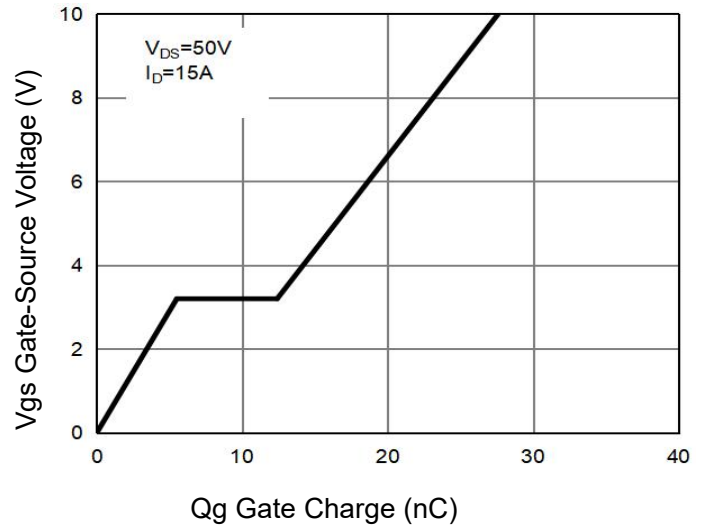
**Figure 2 Transfer Characteristics**



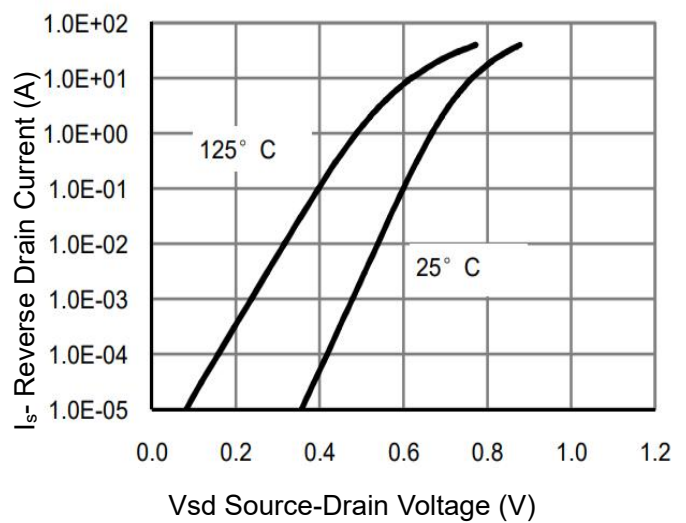
**Figure 3 Rdson- Drain Current**



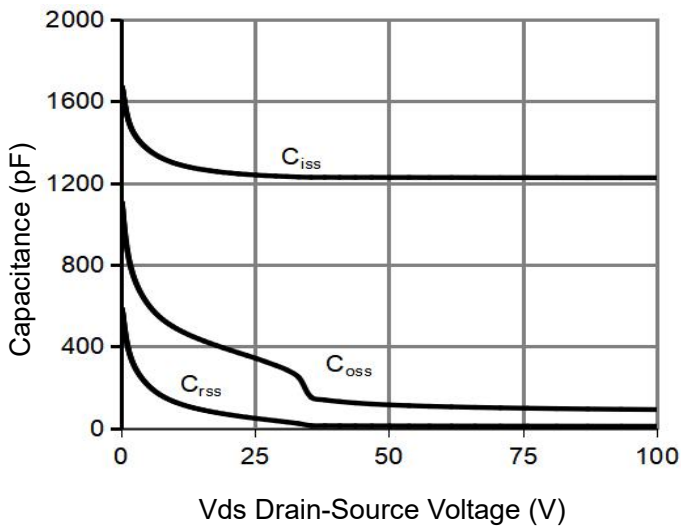
**Figure 4 Rdson-Junction Temperature**



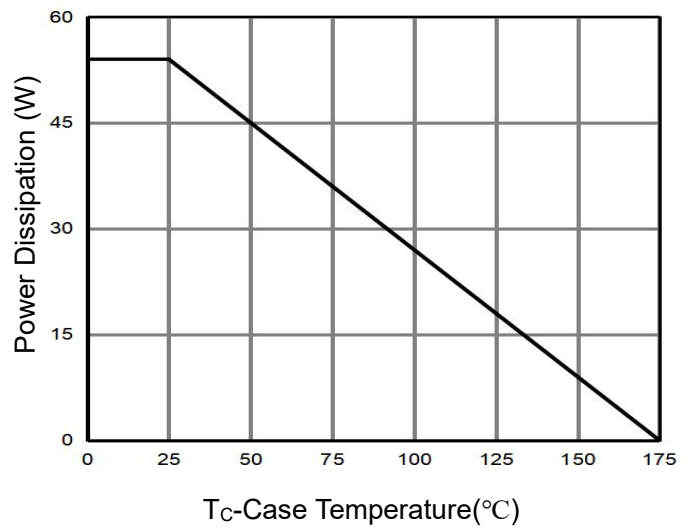
**Figure 5 Gate Charge**



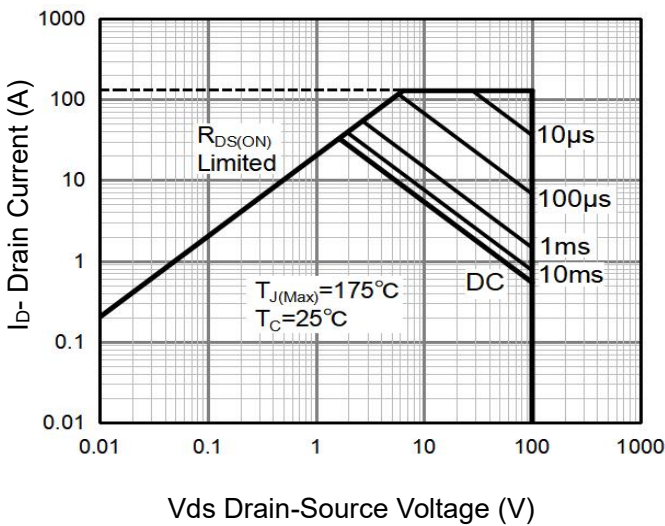
**Figure 6 Source- Drain Diode Forward**



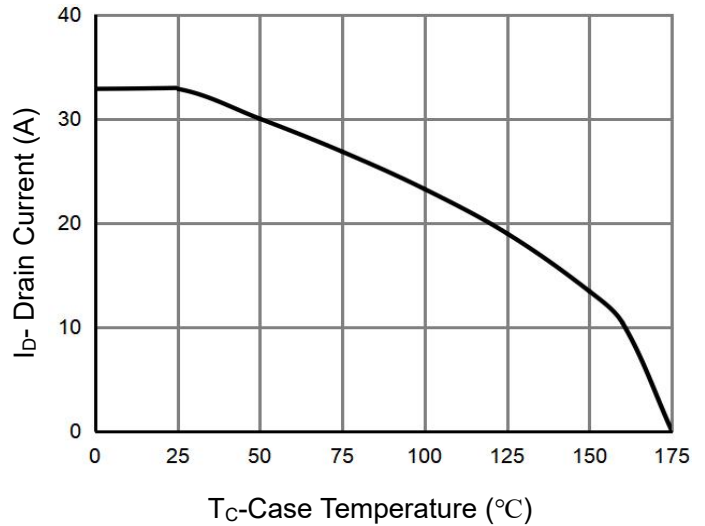
Vds Drain-Source Voltage (V)  
**Figure 7 Capacitance vs Vds**



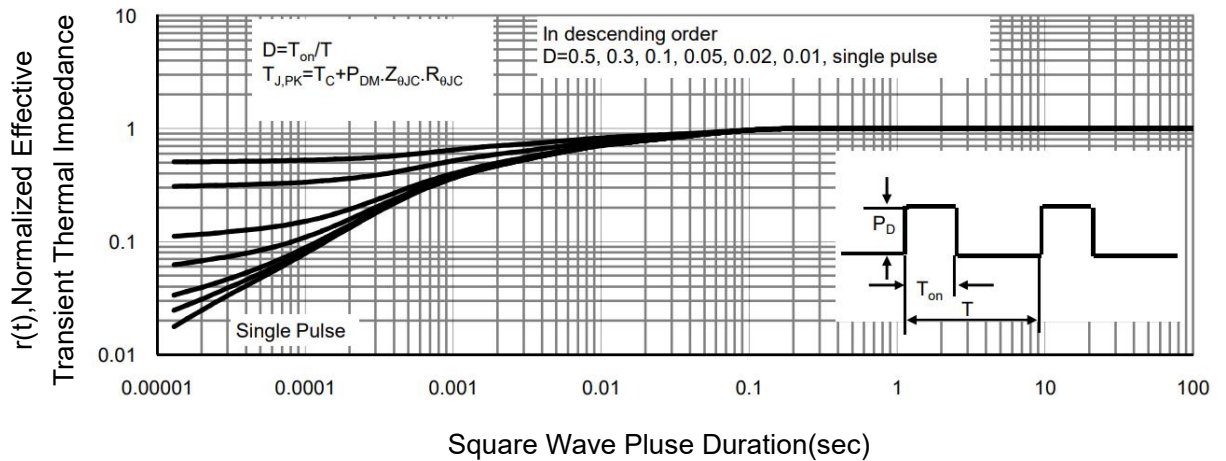
Tc-Case Temperature(°C)  
**Figure 9 Power De-rating**



Vds Drain-Source Voltage (V)  
**Figure 8 Safe Operation Area**

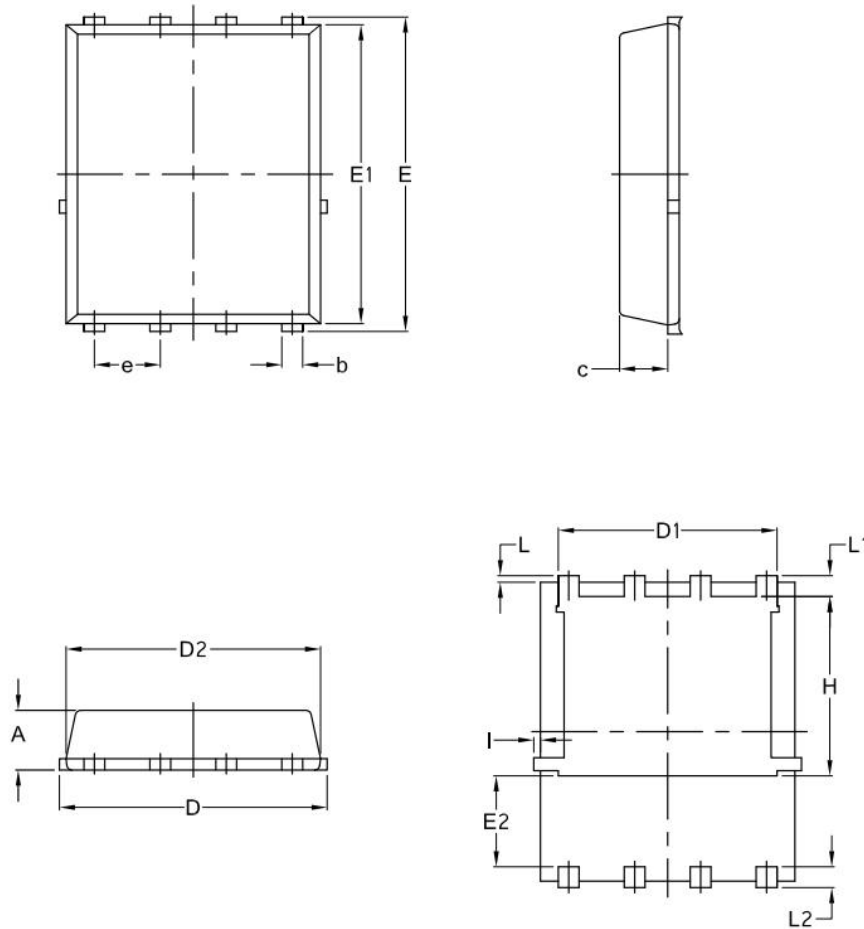


Tc-Case Temperature (°C)  
**Figure 10 Current De-rating**



Square Wave Pulse Duration(sec)  
**Figure 11 Normalized Maximum Transient Thermal Impedance**

## DFN5X6-8L Package Information



SYMBOL	COMMON			
	MM		INCH	
	MIN.	MAX.	MIN.	MAX.
A	1.03	1.17	0.0406	0.0461
b	0.34	0.48	0.0134	0.0189
c	0.824	0.970	0.0324	0.0382
$\Delta$ D	4.80	5.40	0.1890	0.2126
D1	4.11	4.31	0.1618	0.1697
$\Delta$ D2	4.80	5.00	0.1890	0.1969
E	5.95	6.15	0.2343	0.2421
E1	5.65	5.85	0.2224	0.2303
E2	1.60	—	0.0630	—
e	1.27 BSC		0.05 BSC	
$\Delta$ L	0.05	0.25	0.0020	0.0098
L1	0.38	0.50	0.0150	0.0197
L2	0.38	0.50	0.0150	0.0197
$\Delta$ H	3.30	3.50	0.1299	0.1378
I	—	0.18	—	0.0070

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